Product data sheet

1. General description

Silicon Carbide Schottky diode in a DFN 8*8 plastic package, designed for high frequency switched-mode power supplies.



2. Features and benefits

- · Highly stable switching performance
- Extremely fast reverse recovery time
- Superior in efficiency to Silicon Diode alternatives
- · Reduced losses in associated MOSFET
- Reduced EMI
- · Reduced cooling requirements
- RoHS compliant

3. Applications

- · Power factor correction
- Telecom / Server SMPS
- UPS
- PV inverter
- PC Silverbox
- LED / OLED TV
- Motor Drives

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Va	lues		Unit
Absolute	maximum rating						
V_{RRM}	repetitive peak reverse voltage			6	50		V
I _{F(AV)}	average forward current	δ = 0.5 ; square-wave pulse; $T_c \le 138$ °C; Fig. 1; Fig. 2; Fig. 3			10		А
T _j	junction temperature			1	75		°C
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Static ch	aracteristics						
V_{F}	forward voltage	I _F = 10 A; T _j = 25 °C; <u>Fig. 5</u>		-	1.5	1.7	V
		I _F = 10 A; T _j = 150 °C; <u>Fig. 5</u>		-	1.8	2.2	V
Dynamic	characteristics		•				
Q _r	recovered charge	$I_F = 10 \text{ A}$; $dI_F/dt = 500 \text{ A}/\mu\text{s}$; $V_R = 400 \text{ V}$; $T_j = 25 ^{\circ}\text{C}$; Fig. 7		-	14	-	nC

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	n.c.	not connected	[κ_I/I_ Δ
2	n.c.	not connected	5	K — A 001aaa020
3	А	anode		
4	А	anode	<u>8</u>	
5	К	mounting base; connected to cathode	1 2 3 4	

6. Ordering information

Table 3. Ordering information

Type number	Package name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date
WNSC2D10650	Γ DFN8*8	WNSC2D10650TJ	Tape	3000	DFN8X8N	25-Dec-2019

7. Marking

Table 4. Marking codes

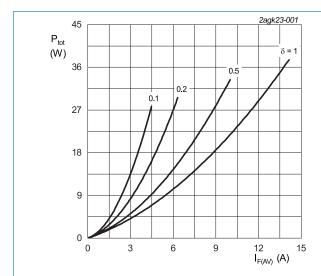
Type number	Marking codes
WNSC2D10650T	WNSC2D 10650T

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Values	Unit
V_{RRM}	repetitive peak reverse voltage		650	V
V_{RWM}	crest working reverse voltage		650	V
V_R	reverse voltage	DC	650	V
I _{F(AV)}	average forward current	$δ$ = 0.5; square-wave pulse; $T_c \le 138$ °C; Fig. 1; Fig. 2; Fig. 3	10	А
I _{FRM}	repetitive peak forward current	δ = 0.5; t_p = 25 μs; T_c ≤ 138 °C; square-wave pulse	20	А
I _{FSM}	non-repetitive peak	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse	50	А
	forward current	t _p = 10 μs; T _{j(init)} = 25 °C; square-wave pulse	450	А
l ² t	I ² t for fusing	sine-wave pulse; $T_{j(init)} = 25 \text{ °C}$; $t_p = 10 \text{ ms}$	12.5	A ² s
T _{stg}	storage temperature		-55 to 175	°C
T _j	junction temperature		175	°C



$$\begin{split} I_{F(AV)} &= I_{F(RMS)} \times \sqrt{\delta} \\ V_o &= 1.024 \text{ V; R}_s = 0.1156 \text{ }\Omega \end{split}$$

Fig. 1. Forward power dissipation as a function of average forward current; square waveform; maximum values

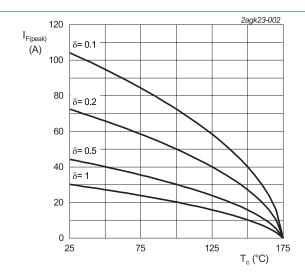
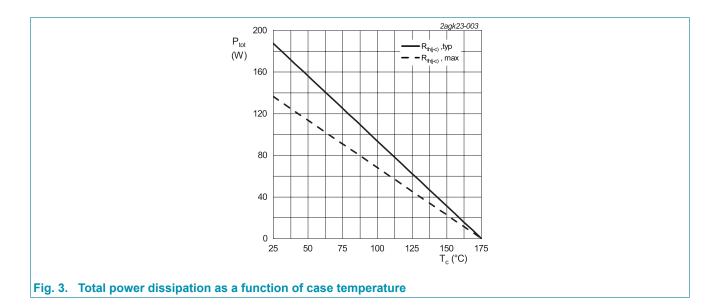


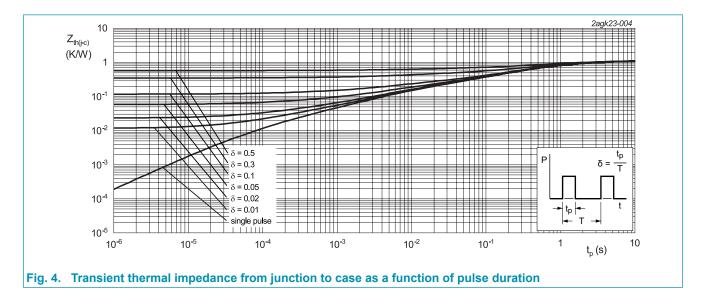
Fig. 2. Current derating as a function of case temperature



9. Thermal characteristics

Table 6. Thermal characteristics

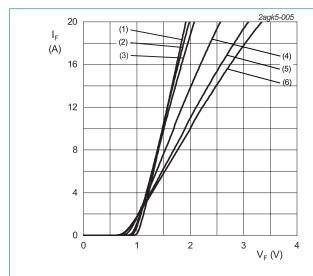
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-c)}	thermal resistance from junction to case	Fig. 4	-	0.8	1.1	K/W
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient free air	in free air	-	50	-	K/W



10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	racteristics					
V_{F}	forward current	I _F = 10 A; T _j = 25 °C; <u>Fig. 5</u>	-	1.5	1.7	V
		I _F = 10 A; T _j = 150 °C; <u>Fig. 5</u>	-	1.8	2.2	V
		I _F = 10 A; T _j = 175 °C; <u>Fig. 5</u>	-	2	2.3	V
I _R	reverse current	V _R = 650 V; T _j = 25 °C; <u>Fig. 6</u>	-	0.5	50	μA
		V _R = 650 V; T _j = 175 °C; <u>Fig. 6</u>	-	25	250	μA
Dynamic	characteristics					
Q _r	recovered charge	$I_F = 10 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 500 \text{ A}/\mu\text{s};$ $T_j = 25 \text{ °C}; Fig. 7$	-	14	-	nC
C _d	diode capacitance	f = 1 MHz; V _R = 1 V; T _j = 25 °C	-	310	-	pF
		f = 1 MHz; V _R = 300 V; T _j = 25 °C	-	36	-	pF
		f = 1 MHz; V _R = 600 V; T _j = 25 °C	-	32	-	pF
E _{as}	non-repetitive avalanche energy	$I_R = 5.5 \text{ A}; L = 5 \text{ mH}; T_{j(init)} = 25 \text{ °C}$	75	-	-	mJ



 V_o = 1.024 V; R_s = 0.1156 Ω

(1) $T_i = -55$ °C; typical values

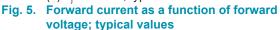
(2) T_j = 0 °C; typical values

(3) T_i = 25 °C; typical values

(4) $T_i = 100 \,^{\circ}\text{C}$; typical values

(5) $T_j = 150$ °C; typical values

(6) T_j = 175 °C; typical values



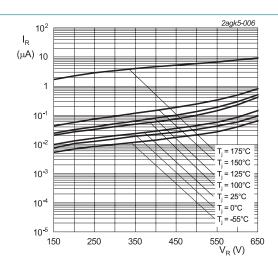
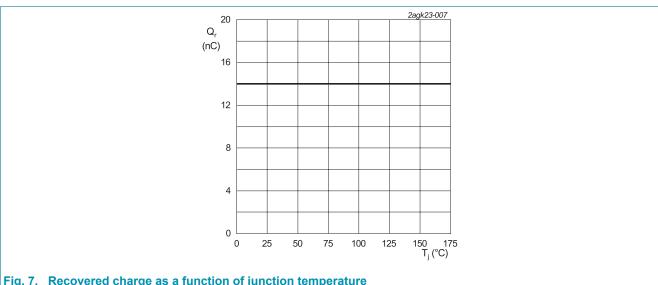
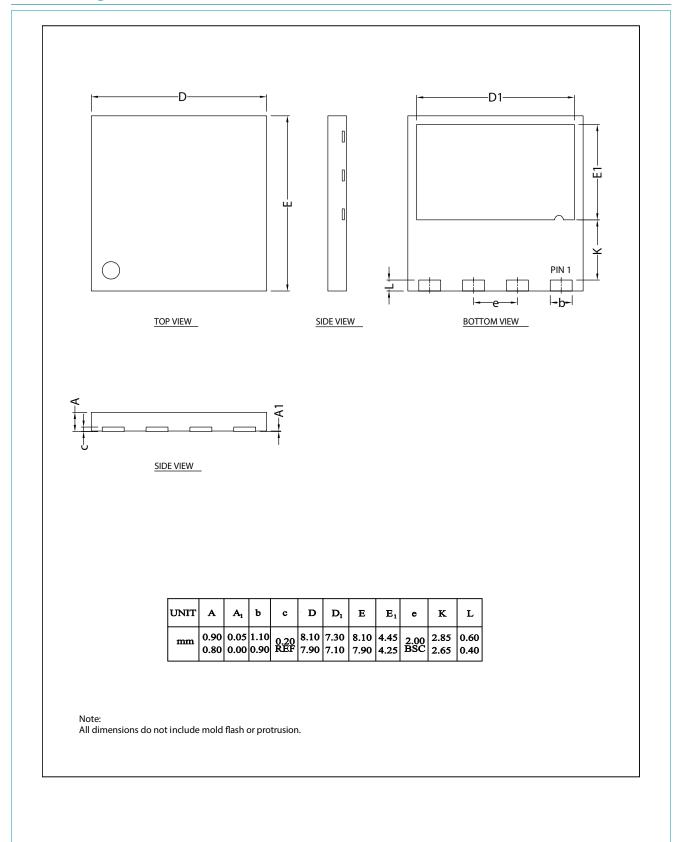


Fig. 6. Reverse leakage current as a function of reverse voltage; typical value



11. Package outline



12. Legal information

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Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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